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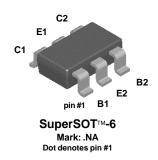
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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

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FMB100



NPN Multi-Chip General Purpose Amplifier

This device is designed for general purpose amplifier applications at collector currents to 300 mA. Sourced from Process 10.

Absolute Maximum Ratings* T_A =25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------------------------------|--|-------------|-------|
| V _{CEO} | Collector-Emitter Voltage | 45 | V |
| V _{CBO} | Collector-Base Voltage | 75 | V |
| V _{EBO} | Emitter-Base Voltage | 6.0 | V |
| Ic | Collector Current - Continuous | 500 | mA |
| T _J , T _{stg} | Operating and Storage Junction Temperature Range | -55 to +150 | °C |

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

| Symbol | Characteristic | Max | Units | |
|-----------------|---|--------|-------|--|
| | | FMB100 | | |
| P _D | Total Device Dissipation | 700 | mW | |
| | Derate above 25°C | 5.6 | mW/°C | |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 180 | °C/W | |

These ratings are based on a maximum junction temperature of 150 degrees C.
 These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

NPN Multi-Chip General Purpose Amplifier

(continued)

| FI | ectri | cal | Ch | ara | cte | rist | ics |
|----|-------|-----|--------------|------|-----|------|-----|
| | CCLI | vai | \mathbf{v} | aı a | ulu | 1131 | |

T_A= 25°C unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Тур | Max | Units |
|--|--|---|-----------|-----|------------|-------|
| OFF CHA | RACTERISTICS | | | | | |
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = 10 \mu A, I_B = 0$ | 75 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage* | I _C = 1 mA, I _E = 0 | 45 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10 \mu A, I_C = 0$ | 6.0 | | | V |
| I _{CBO} | Collector Cutoff Current | V _{CB} = 60 V | | | 50 | nA |
| I _{CES} | Collector Cutoff Current | V _{CE} = 40 V | | | 50 | nA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 4 V | | | 50 | nA |
| h _{FE} | DC Current Gain | $I_C = 100 \mu\text{A}, V_{CE} = 1.0 \text{V}$ $I_C = 10 \text{mA}, V_{CE} = 1.0 \text{V}$ | 80 100 | | 450 | |
| h _{FE} | DC Current Gain | | | | 450 | |
| | | $I_C = 100 \text{ mA}, V_{CF} = 1.0 \text{ V}^*$ | 100 | | 430 | |
| | | $I_C = 150 \text{ mA}, V_{CE} = 5.0 \text{ V}^*$ | 100 | | 350 | |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | $I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$ $I_C = 200 \text{ mA}, I_B = 20 \text{ mA}^*$ | | | 0.2 0.4 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | $I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$ | | | 0.85 | |
| | | $I_C = 200 \text{ mA}, I_B = 20 \text{ mA}^*$ | | | 1.0 | V |
| | IGNAL CHARACTERISTICS | | | | 1.0 | V |
| SMALL SI f _T C _{obo} | GNAL CHARACTERISTICS Current Gain - Bandwidth Product Output Capacitance | V _{CE} = 20 V, I _C = 20 mA V _{CB} = 5.0 V, f = 1.0 MHz | | 300 | 1.0 | |

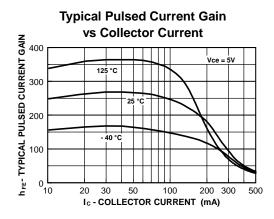
 $I_C = 100 \mu A, V_{CE} = 5.0 V,$

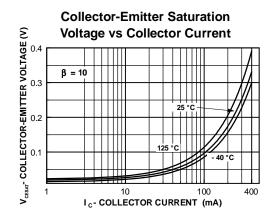
 R_G = 2.0 $k\Omega$, f = 1.0 kHz

Noise Figure

NF

Typical Characteristics





2.5

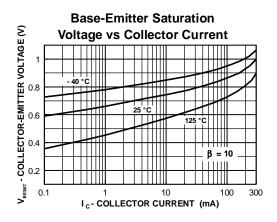
dB

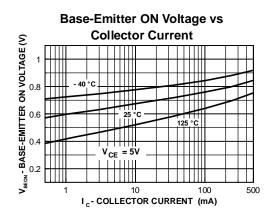
^{*}Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%

NPN Multi-Chip General Purpose Amplifier

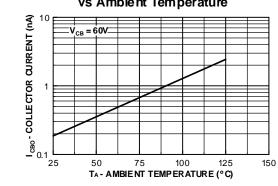
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Typical Characteristics (continued)

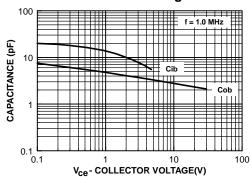




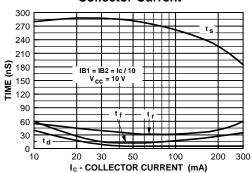
Collector-Cutoff Current vs Ambient Temperature



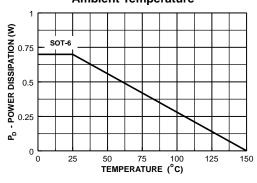
Input and Output Capacitance vs Reverse Voltage



Switching Times vs Collector Current



Power Dissipation vs Ambient Temperature



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|--------------------------|---------------------------|---|--|--|--|
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